

Stepping Motor Driver series

High Voltage Series Stepping Motor Drivers

BD6422EFV (PARALLEL-IN type) BD6425, BD6423EFV (CLK-IN type)

No.12009EAT06

Description

These products are a low power consumption PWM constant current-drive driver of bipolar stepping motor with power supply's rated voltage of 45V and rated output current of 1.0A, 1.5A.

Feature

- 1) Power supply: one system drive (rated voltage of 45V)
- 2) Rated output current: 1.0A, 1.5A
- 3) Low ON resistance DMOS output
- 4) CLK-IN drive mode (BD6425/6423EFV)
- 5) Parallel IN drive mode (BD6422EFV)
- 6) PWM constant current control (other oscillation)
- 7) Built-in spike noise blanking function (external noise filter is unnecessary)
- 8) FULL STEP & HALF STEP (two kinds), applicable to QUARTER STEP
- 9) Current decay mode switching function (4 kinds of FAST/SLOW DECAY ratio)
- 10) Normal rotation & reverse rotation switching function (BD6425/6423EFV)
- 11) Power save function
- 12) Built-in logic input pull-down resistor
- 13) Power-on reset function(BD6425/6423EFV)
- 14) Thermal shutdown circuit (TSD)
- 15) Over current protection circuit (OCP)
- 16) Under voltage lock out circuit (UVLO)
- 17) Malfunction prevention at the time of no applied power supply (Ghost Supply Prevention)
- 18) Electrostatic discharge: 8kV (HBM specification)
- 19) Microminiature, ultra-thin and high heat-radiation (exposed metal type) HTSSOP package

Application

serial dot impact printer, sewing machine etc.

Absolute maximum ratings(Ta=25°C)

Item	Symbol	BD6425EFV	BD6423/6422EFV	Unit
Supply voltage	V _{CC1,2}	-0.2~+45.0	-0.2~+45.0	V
	D.	1.45 ^{%1}	1.1 ^{**3}	W
Power dissipation	Pd	4.70 ^{%2}	4.0 ^{**4}	W
Input voltage for control pin	V _{IN}	-0.2~+5.5	-0.2~+5.5	V
RNF maximum voltage	V _{RNF}	0.7	0.7	V
Maximum output current	IOUT	1.5 ^{**5}	1.0 ^{**5}	A/phase
Operating temperature range	T _{opr}	-25~+85	-25~+85	°C
Storage temperature range	T _{stg}	-55~+150	-55~+150	°C
Junction temperature	T _{imax}	+150	+150	°C

×1 70mm×70mm×1.6mm glass epoxy board. Derating in done at 11.6mW/°C for operating above Ta=25°C.

*2 4-layer recommended board. Derating in done at 37.6mW/°C for operating above Ta=25°C.

3 70mm × 70mm × 1.6mm glass epoxy board. Derating in done at 8.8mW/°C for operating above Ta=25°C.

*4 4-layer recommended board. Derating in done at 32.0mW/°C for operating above Ta=25°C.

%5 Do not, however exceed Pd, ASO and Tjmax=150°C.

●Operating conditions((Ta= -25~+85°C)

Item	Symbol	BD6425EFV	BD6423/6422EFV	Unit
Supply voltage	V _{CC1,2}	19~-	42	V
Maximum Output current (DC)	I _{OUT}	1.2 ^{%6}	0.7 ^{%6}	A/phase

%6 Do not however exceed Pd, ASO.

●Electrical characteristics (Unless otherwise specified Ta=25°C, V_{CC1,2}=37V)

ltem	Sumbol	Limit			Unit	Condition	
nem	Symbol	Min.	Тур.	Max.	Unit	Condition	
Whole	1						
Circuit current at standby	ICCST	-	1.0	2.5	mA	PS=L	
Circuit current	I _{CC}	-	2.0	5.0	mA	PS=H, VREF=3V	
Control input						·	
H level input voltage	VINH	2.0	-	-	V		
L level input voltage	V _{INL}	-	-	0.8	V		
H level input current	I _{INH}	35	50	100	μA	V _{IN} =5V	
L level input current	I _{INL}	-10	0	-	μA	V _{IN} =0V	
Output (OUT1A, OUT1B, OUT2A, OUT2B)						·	
Output ON resistance(BD6425EFV)	R _{ON}	-	1.10	1.43	Ω	I _{OUT} =1.0A,Sum of upper and lower	
Output ON resistance(BD6423/6422EFV)	R _{ON}	-	2.00	2.60	Ω	I _{OUT} =0.5A,Sum of upper and lower	
Output leak current	I _{LEAK}	-	-	10	μA		
Current control						·	
RNFXS input current (BD6425EFV)	I _{RNFS}	-2.0	-0.1	-	μA	RNFXS=0V	
RNFX input current	I _{RNF}	-40	-20	-	μA	RNFX=0V	
VREF input current	I _{VREF}	-2.0	-0.1	-	μA	VREF=0V	
VREF input voltage range	V_{REF}	0	-	3.0	V		
Minimum on time (Blank time)	t _{ONMIN}	0.5	1.5	3.0	μs	C=470pF, R=82kΩ	
BD6425/6423EFV							
Comparator threshold	V _{CTH}	0.57	0.60	0.63	V	VREF=3V	
BD6422EFV						•	
Comparator threshold 100%	V _{CTH100}	0.57	0.60	0.63	V	VREF=3V, (I0X,I1X)=(L,L)	
Comparator threshold 67%	V _{CTH67}	0.38	0.40	0.42	V	VREF=3V, (I0X,I1X)=(H,L)	
Comparator threshold 33%	V _{СТН33}	0.18	0.20	0.22	V	VREF=3V, (I0X,I1X)=(L,H)	

Terminal function and Application circuit diagram

1) BD6425EFV

Pin No.	Pin name	Function	Pin No.	Pin name	Function
1	GND	Ground terminal	15	CLK	Clock input terminal for advancing the electrical angle.
2	OUT1B	H bridge output terminal	16	CW_CCW	Motor rotating direction setting terminal
3	RNF1	Connection terminal of resistor for output current detection	17	TEST	Terminal for testing (used by connecting with GND)
4	RNF1S	Input terminal of current limit comparator	18	MODE0	Motor excitation mode setting terminal
5	OUT1A	H bridge output terminal	19	MODE1	Motor excitation mode setting terminal
6	NC	Non connection	20	ENABLE	Power supply terminal
7	VCC1	Power supply terminal	21	NC	Non connection
8	NC	Non connection	22	VCC2	Power supply terminal
9	GND	Ground terminal	23	NC	Non connection
10	CR	Connection terminal of CR for setting chopping frequency	24	OUT2A	H bridge output terminal
11	DEC1	Current decay mode setting terminal	25	RNF2S	Input terminal of current limit comparator
12	DEC2	Current decay mode setting terminal	26	RNF2	Connection terminal of resistor for output current detection
13	VREF	Output current value setting terminal	27	OUT2B	H bridge output terminal
14	PS	Power save terminal	28	NC	Non connection



2) BD6423EFV

Pin No.	Pin name	Function	Pin No.	Pin name	Function
1	GND	Ground terminal	13	CLK	Clock input terminal for advancing the electrical angle.
2	OUT1B	H bridge output terminal	14	CW_CCW	Motor rotating direction setting terminal
3	RNF1	Connection terminal of resistor for output current detection	15	TEST	Terminal for testing (used by connecting with GND)
4	OUT1A	H bridge output terminal	16	MODE0	Motor excitation mode setting terminal
5	VCC1	Power supply terminal	17	MODE1	Motor excitation mode setting terminal
6	NC	Non connection	18	ENABLE	Output enable terminal
7	GND	Ground terminal	19	NC	Non connection
8	CR	Connection terminal of CR for setting PWM frequency	20	VCC2	Power supply terminal
9	DEC1	Current decay mode setting terminal	21	OUT2A	H bridge output terminal
10	DEC2	Current decay mode setting terminal	22	RNF2	Connection terminal of resistor for output current detection
11	VREF	Output current value setting terminal	23	OUT2B	H bridge output terminal
12	PS	Power save terminal	24	NC	Non connection



Fig.2 Block diagram & Application circuit diagram of BD6423EFV

3) BD6422EFV

Pin	Pin name	Function	Pin	Pin name	Function
No.			No.		
1	GND	Ground terminal	13	PHASE1	Phase selection terminal
2	OUT1B	H bridge output terminal	14	l01	VREF division ratio setting terminal
3	RNF1	Connection terminal of resistor for output current detection	15	I11	VREF division ratio setting terminal
4	OUT1A	H bridge output terminal	16	PHASE2	Phase selection terminal
5	VCC1	Power supply terminal	17	102	VREF division ratio setting terminal
6	NC	Non connection	18	l12	VREF division ratio setting terminal
7	GND	Ground terminal	19	NC	Non connection
8	CR	Connection terminal of CR for setting PWM frequency	20	VCC2	Power supply terminal
9	DEC1	Current decay mode setting terminal	21	OUT2A	H bridge output terminal
10	DEC2	Current decay mode setting terminal	22	RNF2	Connection terminal of resistor for output current detection
11	VREF	Output current value setting terminal	23	OUT2B	H bridge output terminal
12	PS	Power save terminal	24	NC	Non connection



Fig.3 Block diagram & Application circuit diagram of BD6422EFV

Usage Notes

(1) Absolute maximum ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down the devices, thus making impossible to identify breaking mode, such as a short circuit or an open circuit. If any over rated values will expect to exceed the absolute maximum ratings, consider adding circuit protection devices, such as fuses.

(2) Connecting the power supply connector backward

Connecting of the power supply in reverse polarity can damage IC. Take precautions when connecting the power supply lines. An external direction diode can be added.

(3) Power supply Lines

Design PCB layout pattern to provide low impedance GND and supply lines. To obtain a low noise ground and supply line, separate the ground section and supply lines of the digital and analog blocks. Furthermore, for all power supply terminals to ICs, connect a capacitor between the power supply and the GND terminal. When applying electrolytic capacitors in the circuit, not that capacitance characteristic values are reduced at low temperatures.

(4) GND Potential

The potential of GND pin must be minimum potential in all operating conditions.

- (5) Metal on the backside (Define the side where product markings are printed as front) The metal on the backside is shorted with the backside of IC chip therefore it should be connected to GND. Be aware that there is a possibility of malfunction or destruction if it is shorted with any potential other than GND.
- (6) Thermal design

Use a thermal design that allows for a sufficient margin in light of the power dissipation (Pd) in actual operating conditions. Users should be aware that these products have been designed to expose their frames at the back of the package, and should be used with suitable heat dissipation treatment in this area to improve dissipation. As large a dissipation pattern should be taken as possible, not only on the front of the baseboard but also on the back surface. It is important to consider actual usage conditions and to take as large a dissipation pattern as possible.

(7) Inter-pin shorts and mounting errors

When attaching to a printed circuit board, pay close attention to the direction of the IC and displacement. Improper attachment may lead to destruction of the IC. There is also possibility of destruction from short circuits which can be caused by foreign matter entering between outputs or an output and the power supply or GND.

(8) Operation in a strong electric field

Use caution when using the IC in the presence of a strong electromagnetic field as doing so may cause the IC to malfunction.

(9) ASO

When using the IC, set the output transistor so that it does not exceed absolute maximum ratings or ASO.

(10) Thermal shutdown circuit

The IC has a built-in thermal shutdown circuit (TSD circuit). If the chip temperature becomes Tjmax=150°C, and higher, coil output to the motor will be open. The TSD circuit is designed only to shut the IC off to prevent runaway thermal operation. It is not designed to protect or indemnify peripheral equipment. Do not use the TSD function to protect peripheral equipment.

TSD on temperature [°C] (Typ.)	Hysteresis Temperature [°C] (Typ.)
175	25

(11) Inspection of the application board

During inspection of the application board, if a capacitor is connected to a pin with low impedance there is a possibility that it could cause stress to the IC, therefore an electrical discharge should be performed after each process. Also, as a measure again electrostatic discharge, it should be earthed during the assembly process and special care should be taken during transport or storage. Furthermore, when connecting to the jig during the inspection process, the power supply should first be turned off and then removed before the inspection.

(12) Input terminal of IC

This IC is a monolithic IC, and between each element there is a P+ isolation for element partition and a P substrate. This P layer and each element's N layer make up the P-N junction, and various parasitic elements are made up. For example, when the resistance and transistor are connected to the terminal as shown in figure 4,

OWhen GND>(Terminal A) at the resistance and GND>(Terminal B) at the transistor (NPN),

the P-N junction operates as a parasitic diode.

OAlso, when GND>(Terminal B) at the transistor (NPN)

The parasitic NPN transistor operates with the N layers of other elements close to the aforementioned parasitic diode.

Because of the IC's structure, the creation of parasitic elements is inevitable from the electrical potential relationship. The operation of parasitic elements causes interference in circuit operation, and can lead to malfunction and destruction. Therefore, be careful not to use it in a way which causes the parasitic elements to operate, such as by applying voltage that is lower than the GND (P substrate) to the input terminal.



Fig. 4 Pattern Diagram of Parasitic Element

(13) Ground Wiring Patterns

When using both small signal and large current GND patterns, it is recommended to isolate the two ground patterns, placing a single ground point at the application's reference point so that the pattern wiring resistance and voltage variations caused by large currents do not cause variations in the small signal ground voltage. Be careful not to change the GND wiring pattern potential of any external components, either.

(14) TEST Terminal (BD6425/6423EFV)

Be sure to connect TEST pin to GND.

Ordering part number



HTSSOP-B24



HTSSOP-B28



	Notes
	or reproduction of this document, in part or in whole, is permitted without the OHM Co.,Ltd.
The content :	specified herein is subject to change for improvement without notice.
"Products").	specified herein is for the purpose of introducing ROHM's products (hereinafter If you wish to use any such Product, please be sure to refer to the specifications e obtained from ROHM upon request.
illustrate the	application circuits, circuit constants and any other information contained hereir standard usage and operations of the Products. The peripheral conditions musi account when designing circuits for mass production.
However, sh	vas taken in ensuring the accuracy of the information specified in this document ould you incur any damage arising from any inaccuracy or misprint of such ROHM shall bear no responsibility for such damage.
examples of implicitly, any other parties	I information specified herein is intended only to show the typical functions of and application circuits for the Products. ROHM does not grant you, explicitly of y license to use or exercise intellectual property or other rights held by ROHM and B. ROHM shall bear no responsibility whatsoever for any dispute arising from the rechnical information.
equipment o	s specified in this document are intended to be used with general-use electronic r devices (such as audio visual equipment, office-automation equipment, commu- ces, electronic appliances and amusement devices).
The Products	s specified in this document are not designed to be radiation tolerant.
	1 always makes efforts to enhance the quality and reliability of its Products, a fail or malfunction for a variety of reasons.
against the p failure of any shall bear no	The to implement in your equipment using the Products safety measures to guard cossibility of physical injury, fire or any other damage caused in the event of the Product, such as derating, redundancy, fire control and fail-safe designs. ROHM presponsibility whatsoever for your use of any Product outside of the prescribed in accordance with the instruction manual.
system which may result in instrument, t controller or of the Produ	s are not designed or manufactured to be used with any equipment, device of h requires an extremely high level of reliability the failure or malfunction of which a direct threat to human life or create a risk of human injury (such as a medica ransportation equipment, aerospace machinery, nuclear-reactor controller, fuel- other safety device). ROHM shall bear no responsibility in any way for use of any locts for the above special purposes. If a Product is intended to be used for any purpose, please contact a ROHM sales representative before purchasing.
be controlled	to export or ship overseas any Product or technology specified herein that may d under the Foreign Exchange and the Foreign Trade Law, you will be required to use or permit under the Law.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/